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(5-Benzyldibenzo[*b*,*d*]phosphole 5-oxide)trimethylindium

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Abstract

The X-ray crystal structure determination of the title compound, $[In(CH_3)_3(C_{19}H_{15}OP)]$, shows that the In atom has a four-coordinate distorted tetrahedral environment with an In—O bond length of 2.261 (3) Å. The In—O—P linkage is bent with a bond angle of 135.9 (2)°.

Comment

High-purity indium trialkyls have been used extensively in the growth of compound semiconductors by metalorganic chemical vapour deposition (MOCVD). One of the most successful purification methods for indium trialkyls may be called adduct purification, which involves the formation, purification and dissociation of nonvolatile trialkylindium adducts. Donor ligands applied hitherto have mainly been N- and P-containing Lewis bases (Bradley, Chudzynska & Frigo, 1988; Bradley *et al.*, 1988; Foster, Rushworth, Cole-Hamilton, Jones & Stagg, 1988; Moore *et al.*, 1986). In the course of our work on searching for new useful adducts for the purification of indium trialkyls, we isolated the title

compound, (1). The X-ray structure of (1) is presented in Fig. 1.



In contrast to indium halide phosphine oxide complexes, in which indium is six-coordinate with distorted octahedral geometry (Robinson, Wilkins & Zhang, 1990), indium in (1) is four-coordinate in a distorted tetrahedron. The In-O bond length of 2.261 (3) Å is longer than those in $InCl_3(Me_3PO)_3$ $[2.164(11) \text{ Å}], \text{ InCl}_3(\text{Me}_3\text{PO})_2(\text{MeOH}) [2.155(4) \text{ Å}]$ and [InCl₃(Me₃PO)₂(H₂O)]H₂O [2.157 (5) Å]. The trigonal Me₃In molecule undergoes only slight pyramidalization upon coordination of the phosphine oxide [C---In—C = $116.1(2)-120.7(2)^{\circ}$], and therefore no significant change in In-C distances [2.16 (4)-2.25 (6) A for Me₃In (Vranka & Amma, 1967) and 2.158(5)-2.168 (5) Å for (1)] was observed. These data suggest weak interaction between the indium centre and the O atom. Although there are no crystal data available for 5-benzyldibenzo[b,d]phosphole 5-oxide, the P—O bond distance for the oxide should be comparable with that of Ph_3PO . The P-O distance in (1) [1.481(3) A] is almost the same as the P-O bond distance for free Ph_3PO [1.484(1)Å] (Spek, 1987), which should imply only weak π delocalization over P—O—In, if any. In stark contrast to the Al-O-P and Ga-O-P linear linkages in AlMe₃.OPPh₃ (Feher, Budzichowski & Weller, 1993), AlCl₃.OPPh₃ and GaCl₃.OPPh₃ (Burford et al., 1990), In-O-P in (1) is bent with an In-O-P bond angle of 135.9 (2)°. This agrees well with the idea of weak π delocalization over the In—O—P linkage. The P centre in (1) has distorted tetrahedral geometry. Although the P-containing five-membered ring is nearly planar, normal P---C(2) and P--C(12) single-bond distances indicate non-aromatic character of the ring.



Fig. 1. Molecular structure showing 50% probability displacement ellipsoids. H atoms are omitted for clarity.

Experimental

All manipulations were performed in a glove box under purified nitrogen. Solvents were heated under reflux with sodium benzophenone and distilled under nitrogen prior to use. 5-Benzyldibenzo[b,d]phosphole 5-oxide was mixed with trimethylindium in benzene at room temperature. After stirring the mixture at 323 K for 2 h, most of the solvent was removed in vacuum and a white precipitate filtered off. Crystals were obtained by recrystallization from benzene and petroleum ether (303-333 K) (1:2) mixture.

Crystal data

$[In(CH_3)_3(C_{19}H_{15}OP)]$	Mo $K\alpha$ radiation
$M_r = 450.22$	$\lambda = 0.71073 \text{ Å}$
Triclinic	Cell parameters from 25
$P\overline{1}$	reflections
a = 9.089(2) Å	$\theta = 10.26 - 16.94^{\circ}$
b = 9.418(3) Å	$\mu = 1.202 \text{ mm}^{-1}$
c = 12.575 (8) Å	T = 296 K
$\alpha = 89.45 (4)^{\circ}$	Prism
$\beta = 105.25 (3)^{\circ}$	$0.90 \times 0.70 \times 0.40 \text{ mm}$
$\gamma = 91.85(2)^{\circ}$	Colourless
$V = 1038.0(8) \text{ Å}^3$	
Z = 2	
$D_{\rm x} = 1.44 \ {\rm Mg \ m^{-3}}$	

Data collection

 $\omega/2\theta$ scans

1987)

1.000

Enraf-Nonius CAD-4 3353 observed reflections diffractometer $[I > 3\sigma(I)]$ $R_{\rm int} = 0.0117$ Absorption correction: $\theta_{\rm max} = 25^{\circ}$ $h = 0 \rightarrow 10$ ψ scan (Molecular Structure Corporation, $k = -11 \rightarrow 11$ $l = -14 \rightarrow 14$ $T_{\min} = 0.948, T_{\max} =$ 3 standard reflections monitored every 300 3896 measured reflections reflections 3641 independent reflections intensity decay: 1.7%

Refinement

Refinement on F	$(\Delta/\sigma)_{\rm max} = 0.004$
R = 0.044	$\Delta \rho_{\rm max} = 0.76 \ {\rm e} \ {\rm \AA}^{-3}$
wR = 0.057	$\Delta \rho_{\rm min} = -1.03 \ {\rm e} \ {\rm \AA}^{-3}$
S = 1.90	Extinction correction: none
3353 reflections	Atomic scattering factors
226 parameters	from International Tables
H-atom parameters not	for X-ray Crystallography
refined	(1974, Vol. IV)
$w = 1/\sigma^2(F)$	

Table 1. Fractional atomic coordinates and equivalent isotropic displacement parameters $(Å^2)$

$$B_{\rm eq} = (8\pi^2/3)\sum_i\sum_j U_{ij}a_i^*a_j^*\mathbf{a}_i.\mathbf{a}_j$$

х	у	Z	Bea
1.01482(3)	0.15638(3)	0.13305 (2)	3.99 (2)
0.8401 (1)	0.4013 (1)	0.26165 (7)	3.07 (3)
0.9748 (3)	0.3312 (3)	0.2433 (2)	4.2(1)
0.8767 (4)	0.5646 (4)	0.3375 (3)	3.3(1)
0.9508 (5)	0.6873 (4)	0.3163 (3)	4.3(2)
0.9565 (6)	0.8041 (5)	0.3826 (4)	5.3(2)
	x 1.01482 (3) 0.8401 (1) 0.9748 (3) 0.8767 (4) 0.9508 (5) 0.9565 (6)	$\begin{array}{cccc} x & y \\ 1.01482 (3) & 0.15638 (3) \\ 0.8401 (1) & 0.4013 (1) \\ 0.9748 (3) & 0.3312 (3) \\ 0.8767 (4) & 0.5646 (4) \\ 0.9508 (5) & 0.6873 (4) \\ 0.9565 (6) & 0.8041 (5) \end{array}$	$\begin{array}{ccccc} x & y & z \\ 1.01482 (3) & 0.15638 (3) & 0.13305 (2) \\ 0.8401 (1) & 0.4013 (1) & 0.26165 (7) \\ 0.9748 (3) & 0.3312 (3) & 0.2433 (2) \\ 0.8767 (4) & 0.5646 (4) & 0.3375 (3) \\ 0.9508 (5) & 0.6873 (4) & 0.3163 (3) \\ 0.9565 (6) & 0.8041 (5) & 0.3826 (4) \end{array}$

C(4)	0.8918 (6)	0.7971 (5)	0.4698 (4)	5.5(2)
C(5)	0.8158 (6)	0.6743 (5)	0.4911 (3)	4.7 (2)
C(6)	0.8082 (4)	0.5559 (4)	0.4256 (3)	3.3(1)
C(7)	0.7367 (4)	0.4159 (4)	0.4355 (3)	3.6(1)
C(8)	0.6629 (5)	0.3751 (5)	0.5158 (3)	5.1 (2)
C(9)	0.6065 (6)	0.2379 (6)	0.5157 (4)	6.1 (2)
C(10)	0.6204 (6)	0.1411 (5)	0.4380 (4)	5.9 (2)
C(11)	0.6915 (5)	0.1806 (5)	0.3571 (4)	4.8 (2)
C(12)	().7468 (4)	0.3183 (4)	0.3569 (3)	3.4 (1)
C(13)	().6972 (4)	0.4348 (4)	0.1331 (3)	3.7(1)
C(14)	0.5699 (4)	0.5207 (4)	0.1488 (3)	3.4(1)
C(15)	0.4430(5)	0.4572 (5)	0.1731 (3)	4.5 (2)
C(16)	0.3291 (5)	0.5392 (7)	0.1914 (4)	5.9 (2)
C(17)	0.3390 (6)	0.6834 (7)	0.1854 (5)	6.4 (2)
C(18)	0.4625 (6)	0.7473 (5)	0.1607 (5)	6.0 (2)
C(19)	0.5766 (5)	0.6656 (4)	0.1410(3)	4.4 (2)
C(20)	0.7997 (6)	0.0373 (5)	0.1023 (4)	5.8 (2)
C(21)	1.2176 (6)	0.0777 (6)	0.2467 (5)	6.3 (2)
C(22)	1.0507 (6)	0.2870 (6)	-0.0004(4)	5.7 (2)

Table 2. Selected geometric parameters (Å, °)

In—C(22)	2.158 (5)	ln—O	2.261 (3)
In—C(20)	2.168 (5)	PC(1)	1.793 (4)
Р—О	1.481 (3)	PC(13)	1.819(4)
P-C(12)	1.800(3)	C(6)-C(7)	1.469 (5)
InC(21)	2.161 (5)		
C(22)—In—C(21)	116.1 (2)	C(22)—In—C(20)	116.6(2)
C(22)—In—O	98.4 (2)	C(21)—In—C(20)	120.7 (2)
C(21)—In—O	96.3 (2)	C(20)—ln—O	100.9(2)
OPC(1)	116.4 (2)	O-P-C(12)	117.4(2)
O-P-C(13)	112.1 (2)	C(1) - P - C(12)	93.1 (2)
C(1) - P - C(13)	107.5 (2)	C(12) - P - C(13)	108.5 (2)
P—O—In	135.9 (2)	C(2) - C(1) - C(6)	121.5 (3)
C(2)—C(1)—P	129.2 (3)	C(6)C(1)P	109.2 (3)
C(5) - C(6) - C(1)	118.4 (4)	C(5)-C(6)-C(7)	128.2 (3)
C(1) - C(6) - C(7)	113.3 (3)	C(12)-C(7)-C(8)	118.8 (4)
C(12)—C(7)—C(6)	114.9 (3)	C(8)—C(7)—C(6)	126.3 (4)
C(11) - C(12) - C(7)	122.3 (3)	C(11)-C(12)-P	128.4 (3)
C(7) - C(12) - P	109.2 (3)		

The structure was solved by the heavy-atom method and refined by full-matrix least-squares techniques. H atoms were placed in calculated positions and not used for correction of the structure.

Data collection: CAD-4 Software (Enraf-Nonius, 1989). Cell refinement: CAD-4 Software. Data reduction: TEXSAN PROCESS (Molecular Structure Corporation, 1987). Program(s) used to solve structure: DIRDIF (Beurskens et al., 1984). Program(s) used to refine structure: TEXSAN LS, TEXSAN FOUR. Molecular graphics: ORTEPII (Johnson, 1976).

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Lists of structure factors, least-squares-planes data, anisotropic displacement parameters, H-atom coordinates and complete geometry, together with a packing diagram, have been deposited with the IUCr (Reference: KH1081). Copies may be obtained through The Managing Editor, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.

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Bis(triphenylphosphin)iminium-Tetrakis-(pentafluorphenyl)gallat

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Abstract

The crystal structure of bis(triphenylphosphine)iminium tetrakis (pentafluorophenyl)gallate, $[N \{P(C_6H_5)_3\}_2]$ [Ga(C₆F₅)₄], has been determined by X-ray diffraction methods. The tetrakis(pentafluorophenyl)gallate anion has almost tetrahedral geometry.

Kommentar

Die Kristallstruktur des Salzes $[PNP][Ga(C_6F_5)_4]$ enthält das Kation $[PNP]^+$ und das Anion $[Ga(C_6F_5)_4]^$ jeweils auf allgemeinen Lagen (Fig. 1). Das Kation zeigt keine strukturellen Besonderheiten. Der zentrale Bindungswinkel, P1—N—P2 = 146,2 (4)°, ist nur wenig größer als der Mittelwert $[142,2(3)^{\circ}]$ von 497 Eintragungen in der CSD (Allen, Kennard & Taylor, 1983). Im Anion $[Ga(C_6F_5)_4]^-$ ist das zentrale Gallium-Atom ungefähr tetraedrisch von den Pentafluorphenylgruppen koordiniert [Mittelwert C—Ga—C = $110(2)^{\circ}$]. Die Gallium-Kohlenstoff-Abstände variieren geringfügig [1,984(8) bis 2,039(8)Å] und bleiben größer als der Mittelwert über die Abstände Ga—C in Vergleichstrukturen mit Gallium-Kohlenstoff-Bindungen [Ga—C = 1,985(2)Å für 760 Fragmente in 290 Verbindungen aus der CSD].



Ein isoliertes Tetraorganylgallat-Anion $[GaR_4]^-$ ist bisher offensichtlich noch nicht strukturell charakterisiert worden, so daß Vergleichsdaten fehlen. In der analogen Gold-Verbindung Bis(triphenylphosphin)iminium-Tetrakis(pentafluorphenyl)gold(III) (Murray et al., 1987) ist das Gold-Atom quadratisch planar koordiniert. Die Verbindung Tetrakis(µ2-dimethylendiphenylphosphin) - tetrakis (pentafluorphenyl) pentagold -(I,II,III) Tetrakis(pentafluorphenyl)gold Dichlormethan-Solvat (Usón, Laguna, Laguna, Jiménez & Jones, 1991) enthält ebenfalls das quadratisch planare Anion $[Au(C_6F_5)_4]^-$. Die drei isostrukturellen Verbindungcn Tetrakis(pentafluorphenyl)silan (Karipides & Foerst, 1978), Tetrakis(pentafluorphenyl)germanium und Tetrakis(pentafluorphenyl)zinn (Karipides, Forman. Thomas & Reed, 1974) sind wie das Tetrakis(pentafluorphenyl)borat-Anion tetraedrisch aufgebaut. In den sechs bisher strukturell charakterisierten Verbindungen mit ausschließlicher Verknüpfung des Galliums mit vier C-Atomen Tetramethyl-bis(μ_2 -phenylethynyl)digallium (Tecle, Ilsley & Oliver, 1981), [Methanido-bis(dimethylphosphonium-methylid)]-dimethylgallium (Schmidbaur, Gasser, Krüger & Sekutowski, 1977), (μ_2 -1,4-Dioxan-O,O')bis{bis(μ_2 -trimethylsilylmethylen)-(1,4-dioxan-O)bis[(trimethylsilyl)methyl]-gallium-lithium} (Uhl, Klinkhammer, Lavh & Massa, 1991), Bis[1,1-(µ2-dimethylgallium)]diferrocen (Lee, Pennington, Laske & Robinson, 1990), Bis(η^5 -cyclopentadienyl)-(μ_2 -methyl)dimethyl(μ_2 - σ^3 -cyclohexen-1,1,2-triyl)gallium-zirconium (Erker, Albrecht, Krüger & Werner, 1992) und Bis(η^5 -cyclopentadienyl)-(μ_2 -methyl)-dimethyl-(μ_2 - σ^3 -benzol-1,1,2triyl)-gallium-zirconium (Erker et al., 1992) ist das Gallium ausnahmslos Teil eines Ringsystems.